

**Digital Attenuator, 15.5 dB, 5-Bit
DC-2.0 GHz**

**AT-280
V5**

Features

- 0.5 dB Attenuation Steps to 15.5 dB
- Ultra Low DC Power Consumption
- Low Intermodulation Product: +45 dBm IP3
- SOIC-16 Plastic Package
- Tape and Reel Packaging Available
- Temperature Stability: +/-0.15 dB from -40°C to +85°C

Description

M/A-COM's AT-280 is a 5-bit, 0.5-dB step GaAs MMIC digital attenuator in a low cost SOIC 16-lead surface mount plastic package. The AT-280 is ideally suited for use where high accuracy, fast switching, very low power consumption and low intermodulation products are required at a low cost.

Typical applications include radio and cellular equipment, wireless LANS, GPS equipment and other gain/level control circuits.

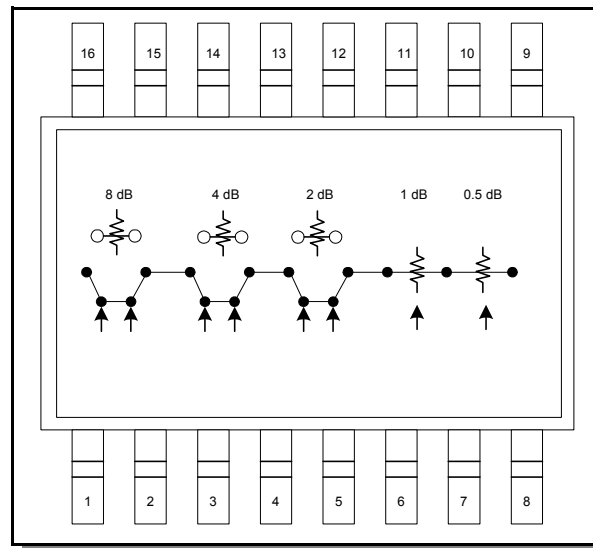
The AT-280 is fabricated with a monolithic GaAs MMIC using a mature 1-micron process. The process features full chip passivation for increased performance and reliability.

Ordering Information ¹

Part Number	Package
AT-280	SOIC 16-Lead
AT-280TR	Forward Tape and Reel
AT-280SMB	Sample Test Board (Includes 5 Samples)

1. Reference Application Note M513 for reel size information.

Functional Schematic



Pin Configuration

Pin No.	Function	Pin No.	Function
1	VC1	9	RF2
2	$\overline{VC1}$	10	Ground
3	VC2	11	Ground
4	$\overline{VC2}$	12	Ground
5	VC3	13	Ground
6	$\overline{VC3}$	14	Ground
7	VC4	15	Ground
8	$\overline{VC5}$	16	RF1

Absolute Maximum Ratings ²

Parameter	Absolute Maximum
Input Power: 0.05 GHz 0.5 - 2.0 GHz	+27 dBm +34 dBm
Control Voltage	-8.5 V \leq V _C \leq +5 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

2. Exceeding any one or combination of these limits may cause permanent damage to this device.

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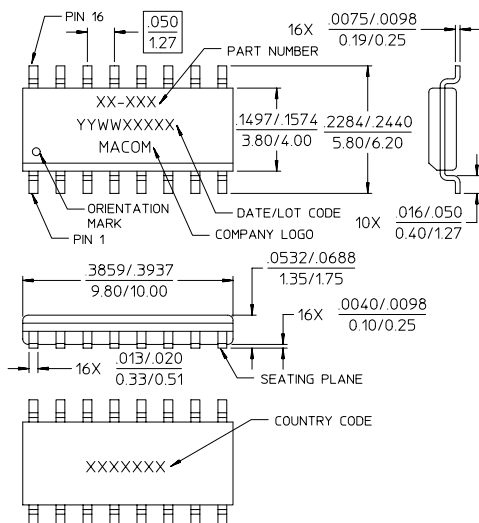
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Electrical Specifications: $T_A = 25^\circ\text{C}$, $Z_0 = 50 \Omega$

Parameter	Test Conditions	Units	Min	Typ	Max
Reference Insertion Loss	DC—0.1 GHz	dB	—	1.1	1.3
	DC—0.5 GHz	dB	—	1.3	1.5
	DC—1.0 GHz	dB	—	1.5	1.8
	DC—2.0 GHz	dB	—	1.8	2.0
Attenuation Accuracy ³	DC—1.0 GHz DC—2.0 GHz	\pm (0.20 dB +3% of Attenuation Setting in dB) dB \pm (0.30 dB +3% of Attenuation Setting in dB) dB			
VSWR	(Any state)	Ratio	1.5:1	1.8:1	—
Trise, Tfall	10% to 90% RF, 90% to 10% RF	nS	—	12	—
Ton, Toff	50% Control to 90% RF, 50% Control to 10% RF	nS	—	18	—
Transients	In Band	mV	—	30	—
1 dB Compression	Input Power, 0.05 GHz	dBm	—	22	—
	Input Power, 0.5 - 2.0 GHz	dBm	—	27	—
IP ₂	0.05 GHz	dBm	—	53	—
	0.5 - 2.0 GHz Measured Relative to Input Power (for two-tone input power up to +5 dBm)	dBm	—	68	—
IP ₃	0.05 GHz	dBm	—	40	—
	0.5 - 2.0 GHz Measured Relative to Input Power (for two-tone input power up to +5 dBm)	dBm	—	45	—

3. Attenuation accuracy specifications apply with negative bias control and low inductance grounding.

SOIC-16



NOTES:
1. REFERENCE JEDEC MS-012-AC FOR ADDITIONAL DIMENSIONAL AND TOLERANCE INFORMATION.
2. REFERENCE M538 APPLICATION NOTE FOR FOOTPRINT INFORMATION.
3. ALL DIMENSIONS SHOWN AS INCHES/MM.

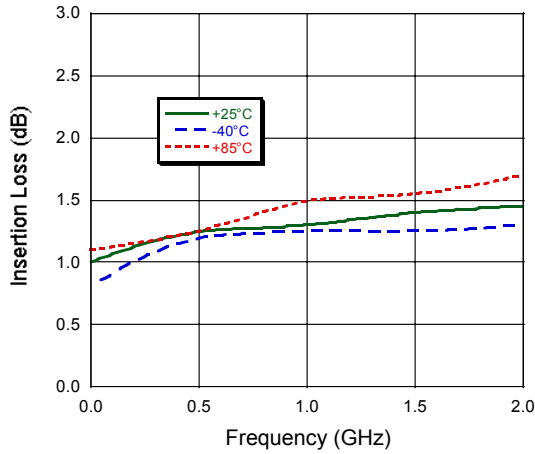
Truth Table^{4,5}

Control Inputs								
$\overline{\text{VC5}}$	$\overline{\text{VC4}}$	$\overline{\text{VC3}}$	VC3	$\overline{\text{VC2}}$	VC2	$\overline{\text{VC1}}$	VC1	Atten. (dB)
1	1	1	0	1	0	1	0	Reference
0	1	1	0	1	0	1	0	0.5 dB
1	0	1	0	1	0	1	0	1 dB
1	1	0	1	1	0	1	0	2 dB
1	1	1	0	0	1	1	0	4 dB
1	1	1	0	1	0	0	1	8 dB
0	0	0	1	0	1	0	1	15.5 dB

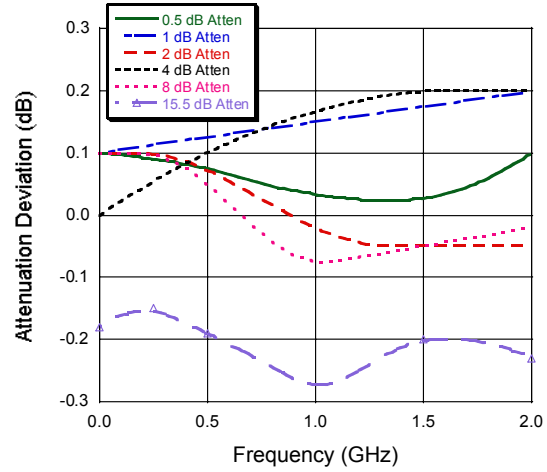
4. 0 = Vin Low = 0 V = 0 to -0.2 V @ 20 μA maximum
5. 1 = Vin High = -5 V at 20 μA to -8 V at 20 μA maximum

Typical Performance Curves

Insertion Loss



Attenuation Accuracy



VSWR

